

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[Texas Instruments](#)

[ULN2003AIDR](#)

For any questions, you can email us directly:

sales@integrated-circuit.com

ULN200x, ULQ200x High-Voltage, High-Current Darlington Transistor Arrays

1 Features

- 500-mA-Rated Collector Current (Single Output)
- High-Voltage Outputs: 50 V
- Output Clamp Diodes
- Inputs Compatible With Various Types of Logic
- Relay-Driver Applications

The ULx2004A devices have a 10.5-k Ω series base resistor to allow operation directly from CMOS devices that use supply voltages of 6 V to 15 V. The required input current of the ULx2004A device is below that of the ULx2003A devices, and the required voltage is less than that required by the ULN2002A device.

2 Applications

- Relay Drivers
- Stepper and DC Brushed Motor Drivers
- Lamp Drivers
- Display Drivers (LED and Gas Discharge)
- Line Drivers
- Logic Buffers

3 Description

The ULx200xA devices are high-voltage, high-current Darlington transistor arrays. Each consists of seven NPN Darlington pairs that feature high-voltage outputs with common-cathode clamp diodes for switching inductive loads.

The collector-current rating of a single Darlington pair is 500 mA. The Darlington pairs can be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers. For 100-V (otherwise interchangeable) versions of the ULx2003A devices, see the [SLRS023](#) data sheet for the SN75468 and SN75469 devices.

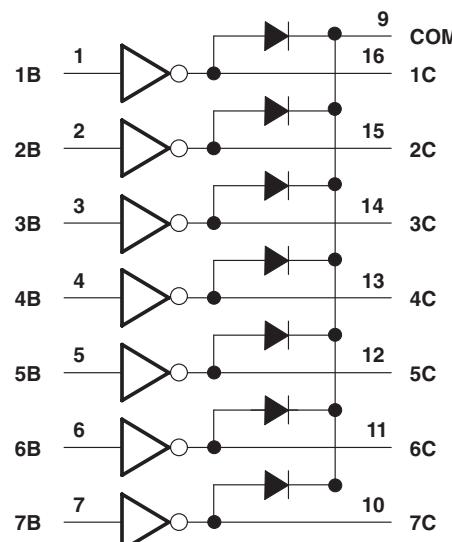
The ULN2002A device is designed specifically for use with 14-V to 25-V PMOS devices. Each input of this device has a Zener diode and resistor in series to control the input current to a safe limit. The ULx2003A devices have a 2.7-k Ω series base resistor for each Darlington pair for operation directly with TTL or 5-V CMOS devices.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
ULx200xD	SOIC (16)	9.90 mm x 3.91 mm
ULx200xN	PDIP (16)	19.30 mm x 6.35 mm
ULN200xNS	SOP (16)	10.30 mm x 5.30 mm
ULN200xPW	TSSOP (16)	5.00 mm x 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Block Diagram



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

**ULN2002A, ULN2003A, ULN2003AI
 ULQ2003A, ULN2004A, ULQ2004A**

SLRS0270 – DECEMBER 1976 – REVISED JANUARY 2016

Table of Contents

1 Features	1	7 Parameter Measurement Information	10
2 Applications	1	8 Detailed Description	12
3 Description	1	8.1 Overview	12
4 Revision History.....	2	8.2 Functional Block Diagrams	12
5 Pin Configuration and Functions	3	8.3 Feature Description.....	13
6 Specifications.....	4	8.4 Device Functional Modes.....	13
6.1 Absolute Maximum Ratings	4	9 Application and Implementation	14
6.2 ESD Ratings.....	4	9.1 Application Information.....	14
6.3 Recommended Operating Conditions	4	9.2 Typical Application	14
6.4 Thermal Information	4	9.3 System Examples	17
6.5 Electrical Characteristics: ULN2002A	5	10 Power Supply Recommendations	18
6.6 Electrical Characteristics: ULN2003A and ULN2004A.....	5	11 Layout.....	18
6.7 Electrical Characteristics: ULN2003AI	6	11.1 Layout Guidelines	18
6.8 Electrical Characteristics: ULN2003AI	6	11.2 Layout Example	18
6.9 Electrical Characteristics: ULQ2003A and ULQ2004A	7	12 Device and Documentation Support	19
6.10 Switching Characteristics: ULN2002A, ULN2003A, ULN2004A.....	7	12.1 Documentation Support	19
6.11 Switching Characteristics: ULN2003AI	7	12.2 Related Links	19
6.12 Switching Characteristics: ULN2003AI	8	12.3 Community Resources.....	19
6.13 Switching Characteristics: ULQ2003A, ULQ2004A	8	12.4 Trademarks	19
6.14 Typical Characteristics	8	12.5 Electrostatic Discharge Caution	19
		12.6 Glossary	19
		13 Mechanical, Packaging, and Orderable Information	19

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision N (June 2015) to Revision O

	Page
• Changed Pin Functions table to correct typographical error.	3

Changes from Revision M (February 2013) to Revision N

	Page
• Added <i>Pin Configuration and Functions</i> section, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section	1
• Deleted <i>Ordering Information</i> table. No specification changes.	1
• Moved <i>Typical Characteristics</i> into <i>Specifications</i> section.	8

Changes from Revision L (April 2012) to Revision M

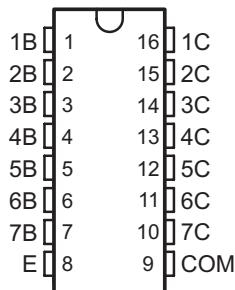
	Page
• Updated temperature rating for ULN2003AI in the ORDERING INFORMATION table	1

Changes from Revision K (August 2011) to Revision L

	Page
• Removed reference to obsolete ULN2001 device.....	1

5 Pin Configuration and Functions

**D, N, NS, and PW Package
 16-Pin SOIC, PDIP, SO, and TSSOP
 Top View**



Pin Functions

PIN		I/O⁽¹⁾	DESCRIPTION
NAME	NO.		
1B	1	I	Channel 1 through 7 Darlington base input
2B	2		
3B	3		
4B	4		
5B	5		
6B	6		
7B	7		
1C	16	O	Channel 1 through 7 Darlington collector output
2C	15		
3C	14		
4C	13		
5C	12		
6C	11		
7C	10		
COM	9	—	Common cathode node for flyback diodes (required for inductive loads)
E	8	—	Common emitter shared by all channels (typically tied to ground)

(1) I = Input, O = Output

**ULN2002A, ULN2003A, ULN2003AI
 ULQ2003A, ULN2004A, ULQ2004A**

SLRS0270 – DECEMBER 1976 – REVISED JANUARY 2016

6 Specifications

6.1 Absolute Maximum Ratings

at 25°C free-air temperature (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Collector-emitter voltage		50	V
	Clamp diode reverse voltage ⁽²⁾		50	V
V _I	Input voltage ⁽²⁾		30	V
	Peak collector current, See Figure 4 and Figure 5		500	mA
I _{OK}	Output clamp current		500	mA
	Total emitter-terminal current		-2.5	A
T _A	Operating free-air temperature range	ULN200xA	-20	70
		ULN200xAI	-40	105
		ULQ200xA	-40	85
		ULQ200xAT	-40	105
T _J	Operating virtual junction temperature		150	°C
	Lead temperature for 1.6 mm (1/16 inch) from case for 10 seconds		260	°C
T _{stg}	Storage temperature	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000
		Charged device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±500

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC}	Collector-emitter voltage (non-V devices)	0	50	V
T _J	Junction temperature	-40	125	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾	ULx200x				UNIT	
	D (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)		
	16 PINS	16 PINS	16 PINS	16 PINS		
R _{θJA}	Junction-to-ambient thermal resistance	73	67	64	108	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	36	54	n/a	33.6	°C/W
R _{θJB}	Junction-to-board thermal resistance	n/a	n/a	n/a	51.9	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	n/a	n/a	n/a	2.1	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	n/a	n/a	n/a	51.4	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics: ULN2002A

$T_A = 25^\circ\text{C}$

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULN2002A			UNIT
			MIN	TYP	MAX	
$V_{I(on)}$	ON-state input voltage	Figure 14	$V_{CE} = 2 \text{ V}$, $I_C = 300 \text{ mA}$		13	V
V_{OH}	High-level output voltage after switching	Figure 18	$V_S = 50 \text{ V}$, $I_O = 300 \text{ mA}$	$V_S = 20$		mV
$V_{CE(sat)}$	Collector-emitter saturation voltage	Figure 12	$I_I = 250 \mu\text{A}$, $I_C = 100 \text{ mA}$		0.9	1.1
			$I_I = 350 \mu\text{A}$, $I_C = 200 \text{ mA}$		1	1.3
			$I_I = 500 \mu\text{A}$, $I_C = 350 \text{ mA}$		1.2	1.6
V_F	Clamp forward voltage	Figure 15	$I_F = 350 \text{ mA}$		1.7	2
I_{CEX}	Collector cutoff current	Figure 9	$V_{CE} = 50 \text{ V}$, $I_I = 0$		50	
		Figure 10	$V_{CE} = 50 \text{ V}$, $T_A = 70^\circ\text{C}$	$I_I = 0$	100	
				$V_I = 6 \text{ V}$	500	
$I_{I(off)}$	OFF-state input current	Figure 10	$V_{CE} = 50 \text{ V}$, $I_C = 500 \mu\text{A}$	50	65	μA
I_I	Input current	Figure 11	$V_I = 17 \text{ V}$		0.82	1.25
I_R	Clamp reverse current	Figure 14	$V_R = 50 \text{ V}$, $T_A = 70^\circ\text{C}$		100	
			$V_R = 50 \text{ V}$		50	
C_i	Input capacitance		$V_I = 0$, $f = 1 \text{ MHz}$		25	pF

6.6 Electrical Characteristics: ULN2003A and ULN2004A

$T_A = 25^\circ\text{C}$

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULN2003A			ULN2004A			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{I(on)}$	Figure 14	$V_{CE} = 2 \text{ V}$	$I_C = 125 \text{ mA}$					5	V
			$I_C = 200 \text{ mA}$			2.4		6	
			$I_C = 250 \text{ mA}$			2.7			
			$I_C = 275 \text{ mA}$					7	
			$I_C = 300 \text{ mA}$			3			
			$I_C = 350 \text{ mA}$					8	
V_{OH}	High-level output voltage after switching	Figure 18	$V_S = 50 \text{ V}$, $I_O = 300 \text{ mA}$	$V_S = 20$			$V_S = 20$		mV
$V_{CE(sat)}$	Collector-emitter saturation voltage	Figure 13	$I_I = 250 \mu\text{A}$, $I_C = 100 \text{ mA}$	0.9	1.1	0.9	1.1		V
			$I_I = 350 \mu\text{A}$, $I_C = 200 \text{ mA}$	1	1.3	1	1.3		
			$I_I = 500 \mu\text{A}$, $I_C = 350 \text{ mA}$	1.2	1.6	1.2	1.6		
I_{CEX}	Collector cutoff current	Figure 9	$V_{CE} = 50 \text{ V}$, $I_I = 0$		50		50		μA
		Figure 10	$V_{CE} = 50 \text{ V}$, $T_A = 70^\circ\text{C}$	$I_I = 0$	100		100		
				$V_I = 6 \text{ V}$			500		
V_F	Clamp forward voltage	Figure 16	$I_F = 350 \text{ mA}$		1.7	2	1.7	2	V
$I_{I(off)}$	Off-state input current	Figure 11	$V_{CE} = 50 \text{ V}$, $T_A = 70^\circ\text{C}$, $I_C = 500 \mu\text{A}$	50	65		50	65	μA
I_I	Input current	Figure 12	$V_I = 3.85 \text{ V}$		0.93	1.35			mA
			$V_I = 5 \text{ V}$				0.35	0.5	
			$V_I = 12 \text{ V}$				1	1.45	
I_R	Clamp reverse current	Figure 15	$V_R = 50 \text{ V}$		50		50		μA
			$V_R = 50 \text{ V}$, $T_A = 70^\circ\text{C}$		100		100		
C_i	Input capacitance		$V_I = 0$, $f = 1 \text{ MHz}$		15	25	15	25	pF

**ULN2002A, ULN2003A, ULN2003AI
 ULQ2003A, ULN2004A, ULQ2004A**

SLRS0270 – DECEMBER 1976 – REVISED JANUARY 2016

www.ti.com

6.7 Electrical Characteristics: ULN2003AI

$T_A = 25^\circ\text{C}$

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULN2003AI			UNIT	
			MIN	TYP	MAX		
$V_{I(on)}$ ON-state input voltage	Figure 14	$V_{CE} = 2 \text{ V}$	$I_C = 200 \text{ mA}$		2.4	V	
			$I_C = 250 \text{ mA}$		2.7		
			$I_C = 300 \text{ mA}$		3		
V_{OH} High-level output voltage after switching	Figure 18	$V_S = 50 \text{ V}, I_O = 300 \text{ mA}$	$V_S - 50$			mV	
$V_{CE(sat)}$ Collector-emitter saturation voltage	Figure 13	$I_I = 250 \mu\text{A}, I_C = 100 \text{ mA}$ $I_I = 350 \mu\text{A}, I_C = 200 \text{ mA}$ $I_I = 500 \mu\text{A}, I_C = 350 \text{ mA}$	0.9	1.1		V	
			1	1.3			
			1.2	1.6			
I_{CEX} Collector cutoff current	Figure 9	$V_{CE} = 50 \text{ V}, I_I = 0$			50	μA	
V_F Clamp forward voltage	Figure 16	$I_F = 350 \text{ mA}$			1.7	2	V
$I_{I(off)}$ OFF-state input current	Figure 11	$V_{CE} = 50 \text{ V}, I_C = 500 \mu\text{A}$	50	65		μA	
I_I Input current	Figure 12	$V_I = 3.85 \text{ V}$			0.93	1.35	mA
I_R Clamp reverse current	Figure 15	$V_R = 50 \text{ V}$			50	μA	
C_I Input capacitance		$V_I = 0, f = 1 \text{ MHz}$			15	25	pF

6.8 Electrical Characteristics: ULN2003AI

$T_A = -40^\circ\text{C to } 105^\circ\text{C}$

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULN2003AI			UNIT	
			MIN	TYP	MAX		
$V_{I(on)}$ ON-state input voltage	Figure 14	$V_{CE} = 2 \text{ V}$	$I_C = 200 \text{ mA}$		2.7	V	
			$I_C = 250 \text{ mA}$		2.9		
			$I_C = 300 \text{ mA}$		3		
V_{OH} High-level output voltage after switching	Figure 18	$V_S = 50 \text{ V}, I_O = 300 \text{ mA}$	$V_S - 50$			mV	
$V_{CE(sat)}$ Collector-emitter saturation voltage	Figure 13	$I_I = 250 \mu\text{A}, I_C = 100 \text{ mA}$ $I_I = 350 \mu\text{A}, I_C = 200 \text{ mA}$ $I_I = 500 \mu\text{A}, I_C = 350 \text{ mA}$	0.9	1.2		V	
			1	1.4			
			1.2	1.7			
I_{CEX} Collector cutoff current	Figure 9	$V_{CE} = 50 \text{ V}, I_I = 0$			100	μA	
V_F Clamp forward voltage	Figure 16	$I_F = 350 \text{ mA}$			1.7	2.2	V
$I_{I(off)}$ OFF-state input current	Figure 11	$V_{CE} = 50 \text{ V}, I_C = 500 \mu\text{A}$	30	65		μA	
I_I Input current	Figure 12	$V_I = 3.85 \text{ V}$			0.93	1.35	mA
I_R Clamp reverse current	Figure 15	$V_R = 50 \text{ V}$			100	μA	
C_I Input capacitance		$V_I = 0, f = 1 \text{ MHz}$			15	25	pF

6.9 Electrical Characteristics: ULQ2003A and ULQ2004A

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULQ2003A			ULQ2004A			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
$V_{I(on)}$ ON-state input voltage	Figure 14	$V_{CE} = 2\text{ V}$	$I_C = 125\text{ mA}$					5	V	
			$I_C = 200\text{ mA}$			2.7		6		
			$I_C = 250\text{ mA}$			2.9				
			$I_C = 275\text{ mA}$					7		
			$I_C = 300\text{ mA}$			3				
			$I_C = 350\text{ mA}$					8		
V_{OH} High-level output voltage after switching	Figure 18	$V_S = 50\text{ V}$, $I_O = 300\text{ mA}$	$V_S - 50$			$V_S - 50$			mV	
$V_{CE(sat)}$ Collector-emitter saturation voltage	Figure 13	$I_I = 250\text{ }\mu\text{A}$, $I_C = 100\text{ mA}$	0.9	1.2		0.9	1.1		V	
		$I_I = 350\text{ }\mu\text{A}$, $I_C = 200\text{ mA}$	1	1.4		1	1.3			
		$I_I = 500\text{ }\mu\text{A}$, $I_C = 350\text{ mA}$	1.2	1.7		1.2	1.6			
I_{CEX} Collector cutoff current	Figure 9 Figure 10	$V_{CE} = 50\text{ V}$, $I_I = 0$	100			50			μA	
		$V_{CE} = 50\text{ V}$, $T_A = 70^\circ\text{C}$, $I_I = 0$				100				
		$V_I = 6\text{ V}$				500				
V_F Clamp forward voltage	Figure 16	$I_F = 350\text{ mA}$	1.7	2.3		1.7	2		V	
$I_{I(off)}$ OFF-state input current	Figure 11	$V_{CE} = 50\text{ V}$, $T_A = 70^\circ\text{C}$, $I_C = 500\text{ }\mu\text{A}$	65			50	65		μA	
I_I Input current	Figure 12	$V_I = 3.85\text{ V}$	0.93	1.35					mA	
		$V_I = 5\text{ V}$				0.35	0.5			
		$V_I = 12\text{ V}$				1	1.45			
I_R Clamp reverse current	Figure 15	$V_R = 50\text{ V}$, $T_A = 25^\circ\text{C}$	100			50			μA	
		$V_R = 50\text{ V}$	100			100				
C_i Input capacitance		$V_I = 0$, $f = 1\text{ MHz}$	15	25		15	25		pF	

6.10 Switching Characteristics: ULN2002A, ULN2003A, ULN2004A

$T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	ULN2002A, ULN2003A, ULN2004A			UNIT
		MIN	TYP	MAX	
t_{PLH} Propagation delay time, low- to high-level output	See Figure 17		0.25	1	μs
t_{PHL} Propagation delay time, high- to low-level output	See Figure 17		0.25	1	μs

6.11 Switching Characteristics: ULN2003AI

$T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	ULN2003AI			UNIT
		MIN	TYP	MAX	
t_{PLH} Propagation delay time, low- to high-level output	See Figure 17		0.25	1	μs
t_{PHL} Propagation delay time, high- to low-level output	See Figure 17		0.25	1	μs

**ULN2002A, ULN2003A, ULN2003AI
 ULQ2003A, ULN2004A, ULQ2004A**

SLRS0270 – DECEMBER 1976 – REVISED JANUARY 2016

6.12 Switching Characteristics: ULN2003AI

$T_A = -40^\circ\text{C}$ to 105°C

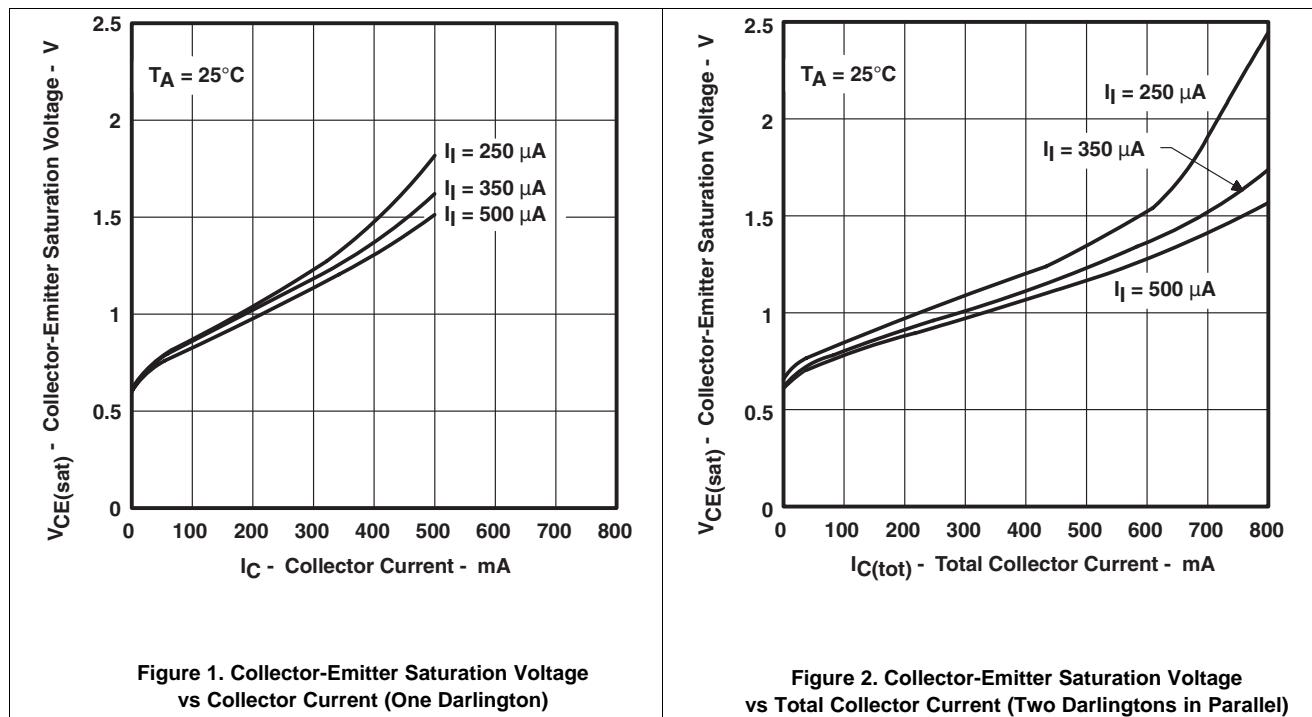
PARAMETER	TEST CONDITIONS	ULN2003AI			UNIT
		MIN	TYP	MAX	
t_{PLH}	Propagation delay time, low- to high-level output	See Figure 17		1	10 μs
t_{PHL}	Propagation delay time, high- to low-level output	See Figure 17		1	10 μs

6.13 Switching Characteristics: ULQ2003A, ULQ2004A

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	ULQ2003A, ULQ2004A			UNIT
		MIN	TYP	MAX	
t_{PLH}	Propagation delay time, low- to high-level output	See Figure 17		1	10 μs
t_{PHL}	Propagation delay time, high- to low-level output	See Figure 17		1	10 μs

6.14 Typical Characteristics



Typical Characteristics (continued)

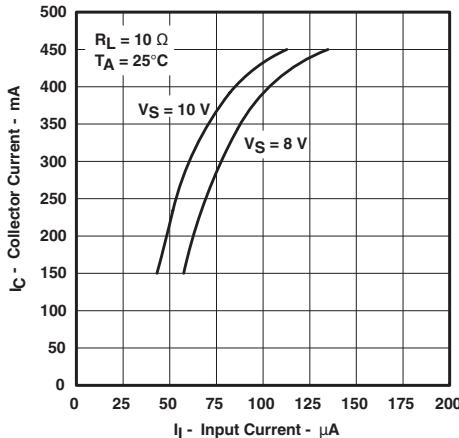


Figure 3. Collector Current vs Input Current

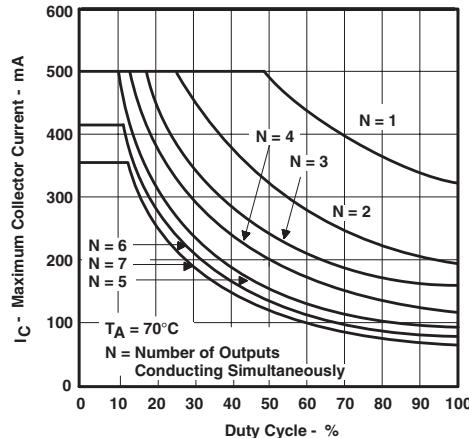


Figure 4. D Package Maximum Collector Current vs Duty Cycle

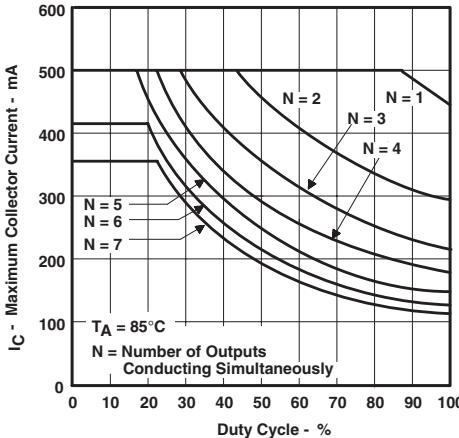


Figure 5. N Package Maximum Collector Current vs Duty Cycle

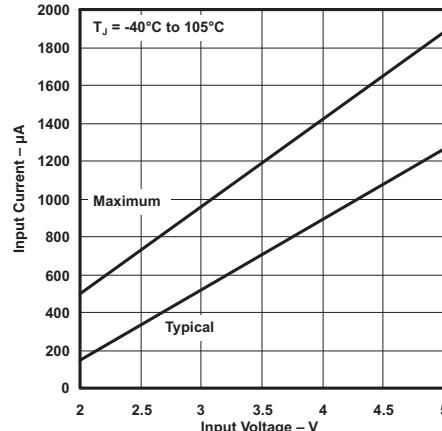


Figure 6. Maximum and Typical Input Current vs Input Voltage

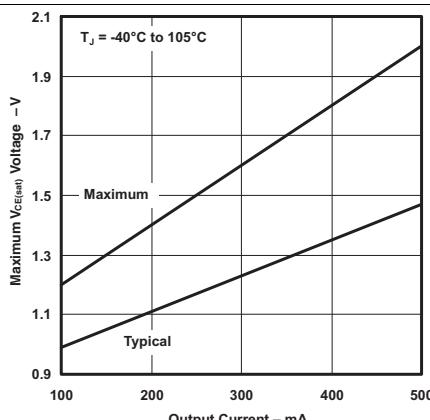


Figure 7. Maximum and Typical Saturated $V_{CE(\text{sat})}$ vs Output Current

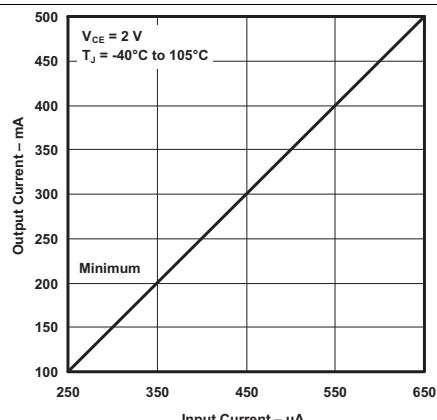


Figure 8. Minimum Output Current vs Input Current

ULN2002A, ULN2003A, ULN2003AI
ULQ2003A, ULN2004A, ULQ2004A

SLRS0270 – DECEMBER 1976 – REVISED JANUARY 2016

www.ti.com

7 Parameter Measurement Information

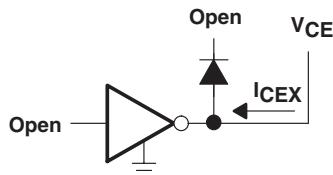


Figure 9. I_{CEx} **Test Circuit**

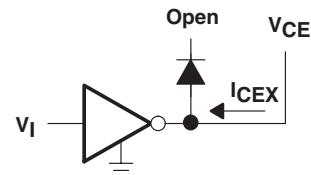


Figure 10. I_{CEx} **Test Circuit**

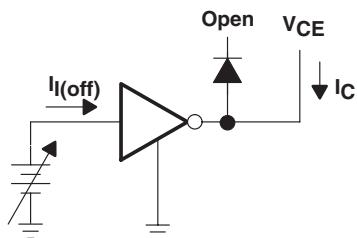


Figure 11. $I_{I(off)}$ **Test Circuit**

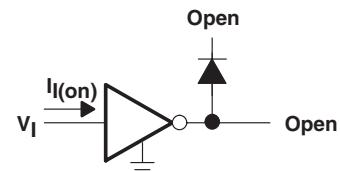


Figure 12. I_I **Test Circuit**

I_I is fixed for measuring $V_{CE(sat)}$, variable for measuring h_{FE} .

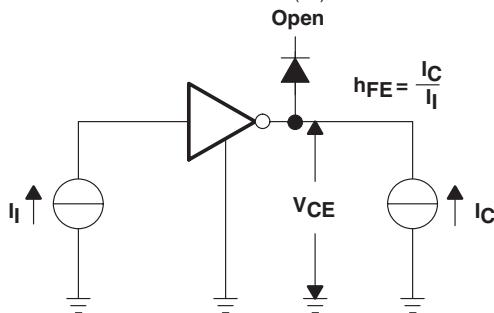


Figure 13. h_{FE} , $V_{CE(sat)}$ **Test Circuit**

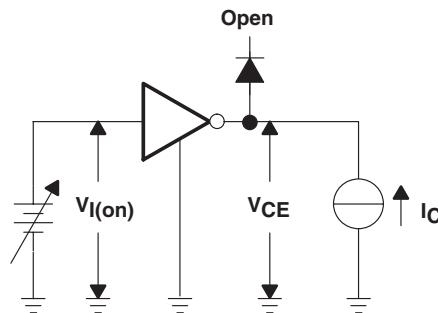


Figure 14. $V_{I(on)}$ **Test Circuit**

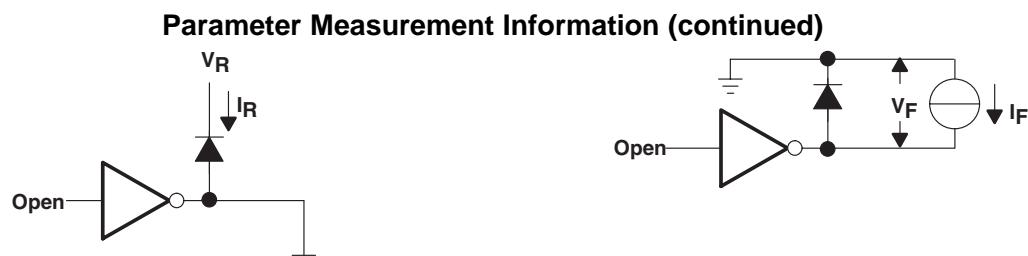


Figure 15. I_R Test Circuit

Figure 16. V_F Test Circuit

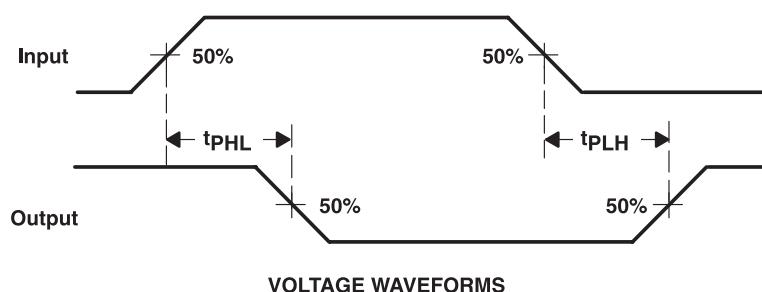
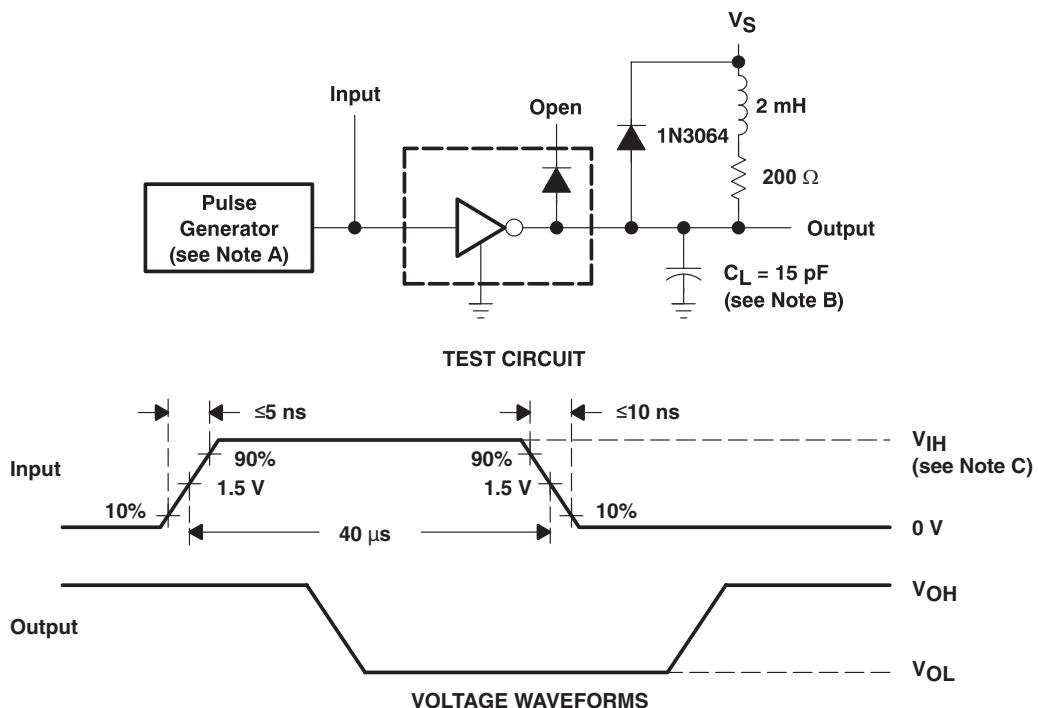


Figure 17. Propagation Delay-Time Waveforms



The pulse generator has the following characteristics: PRR = 12.5 kHz, $Z_0 = 50 \Omega$.

C_L includes probe and jig capacitance.

For testing the ULN2003A device, ULN2003AI device, and ULQ2003A devices, $V_{IH} = 3 \text{ V}$; for the ULN2002A device, $V_{IH} = 13 \text{ V}$; for the ULN2004A and the ULQ2004A devices, $V_{IH} = 8 \text{ V}$.

Figure 18. Latch-Up Test Circuit and Voltage Waveforms

**ULN2002A, ULN2003A, ULN2003AI
 ULQ2003A, ULN2004A, ULQ2004A**

SLRS0270 – DECEMBER 1976 – REVISED JANUARY 2016

8 Detailed Description

8.1 Overview

This standard device has proven ubiquity and versatility across a wide range of applications. This is due to integration of 7 Darlington transistor pairs. All units feature a common emitter and open collector outputs. To maximize their effectiveness, these units contain suppression diodes for inductive loads. The ULN2003A device has a series base resistor to each Darlington pair, thus allowing operation directly with TTL or CMOS operating at supply voltages of 5 V or 3.3 V. The ULN2003A device offers solutions to a great many interface needs, including solenoids, relays, lamps, small motors, and LEDs. Applications requiring sink currents beyond the capability of a single output may be accommodated by paralleling the outputs.

This device can operate over a wide temperature range (-40°C to 105°C).

8.2 Functional Block Diagrams

All resistor values shown are nominal. The collector-emitter diode is a parasitic structure and should not be used to conduct current. If the collectors go below GND, an external Schottky diode should be added to clamp negative undershoots.

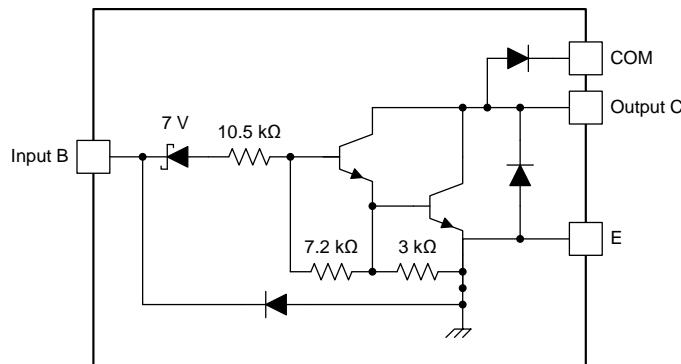


Figure 19. ULN2002A Block Diagram

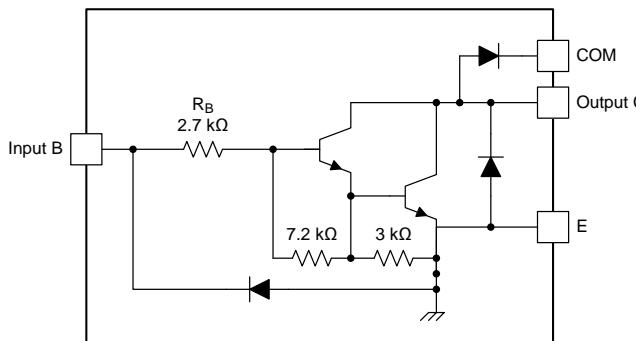


Figure 20. ULN2003A, ULQ2003A and ULN2003AI Block Diagram

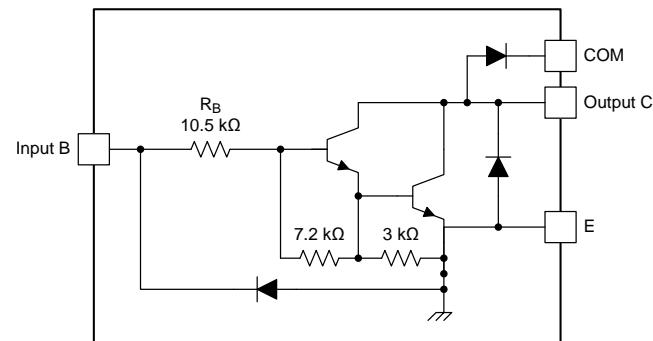


Figure 21. ULN2004A and LQ2004A Block Diagram

8.3 Feature Description

Each channel of the ULN2003A device consists of Darlington connected NPN transistors. This connection creates the effect of a single transistor with a very high-current gain (β_2). This can be as high as 10,000 A/A at certain currents. The very high β allows for high-output current drive with a very low input current, essentially equating to operation with low GPIO voltages.

The GPIO voltage is converted to base current through the 2.7-k Ω resistor connected between the input and base of the predriver Darlington NPN. The 7.2-k Ω and 3-k Ω resistors connected between the base and emitter of each respective NPN act as pulldowns and suppress the amount of leakage that may occur from the input.

The diodes connected between the output and COM pin is used to suppress the kick-back voltage from an inductive load that is excited when the NPN drivers are turned off (stop sinking) and the stored energy in the coils causes a reverse current to flow into the coil supply through the kick-back diode.

In normal operation the diodes on base and collector pins to emitter will be reversed biased. If these diodes are forward biased, internal parasitic NPN transistors will draw (a nearly equal) current from other (nearby) device pins.

8.4 Device Functional Modes

8.4.1 Inductive Load Drive

When the COM pin is tied to the coil supply voltage, ULN2003A device is able to drive inductive loads and suppress the kick-back voltage through the internal free-wheeling diodes.

8.4.2 Resistive Load Drive

When driving a resistive load, a pullup resistor is needed in order for ULN2003A device to sink current and for there to be a logic high level. The COM pin can be left floating for these applications.

**ULN2002A, ULN2003A, ULN2003AI
 ULQ2003A, ULN2004A, ULQ2004A**

SLRS0270 –DECEMBER 1976–REVISED JANUARY 2016

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

Typically, the ULN2003A device drives a high-voltage or high-current (or both) peripheral from an MCU or logic device that cannot tolerate these conditions. This design is a common application of ULN2003A device, driving inductive loads. This includes motors, solenoids and relays. [Figure 22](#) shows a model for each load type.

9.2 Typical Application

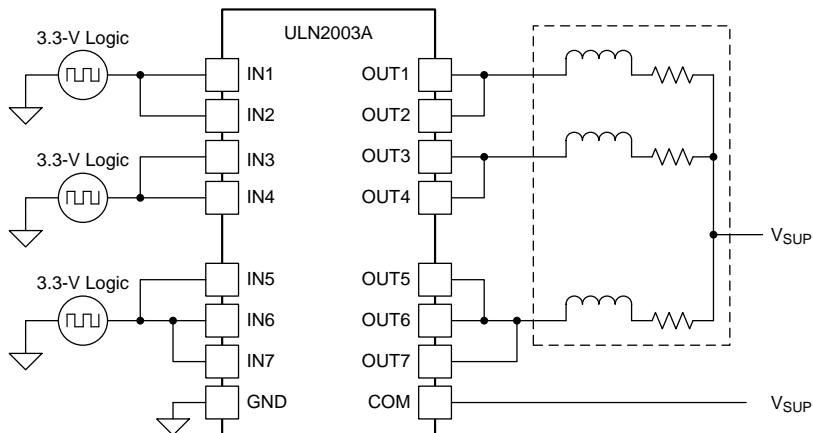


Figure 22. ULN2003A Device as Inductive Load Driver

9.2.1 Design Requirements

For this design example, use the parameters listed in [Table 1](#) as the input parameters.

Table 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
GPIO voltage	3.3 V or 5 V
Coil supply voltage	12 V to 48 V
Number of channels	7
Output current (R_{COIL})	20 mA to 300 mA per channel
Duty cycle	100%

9.2.2 Detailed Design Procedure

When using ULN2003A device in a coil driving application, determine the following:

- Input voltage range
- Temperature range
- Output and drive current
- Power dissipation

9.2.2.1 Drive Current

The coil voltage (V_{SUP}), coil resistance (R_{COIL}), and low-level output voltage ($V_{CE(SAT)}$ or V_{OL}) determine the coil current.

$$I_{COIL} = (V_{SUP} - V_{CE(SAT)}) / R_{COIL} \quad (1)$$

9.2.2.2 Low-Level Output Voltage

The low-level output voltage (V_{OL}) is the same as $V_{CE(SAT)}$ and can be determined by, [Figure 1](#), [Figure 2](#), or [Figure 7](#).

9.2.2.3 Power Dissipation and Temperature

The number of coils driven is dependent on the coil current and on-chip power dissipation. The number of coils driven can be determined by [Figure 4](#) or [Figure 5](#).

For a more accurate determination of number of coils possible, use the below equation to calculate ULN2003A device on-chip power dissipation P_D :

$$P_D = \sum_{i=1}^N V_{OLi} \times I_{Li}$$

where

- N is the number of channels active together
- V_{OLi} is the OUT_i pin voltage for the load current I_{Li} . This is the same as $V_{CE(SAT)}$

To ensure reliability of ULN2003A device and the system, the on-chip power dissipation must be lower than or equal to the maximum allowable power dissipation ($P_{D(MAX)}$) dictated by below equation [Equation 3](#).

$$P_{D(MAX)} = \frac{(T_{J(MAX)} - T_A)}{\theta_{JA}}$$

where

- $T_{J(max)}$ is the target maximum junction temperature
- T_A is the operating ambient temperature
- θ_{JA} is the package junction to ambient thermal resistance

Limit the die junction temperature of the ULN2003A device to less than 125°C. The IC junction temperature is directly proportional to the on-chip power dissipation.

**ULN2002A, ULN2003A, ULN2003AI
 ULQ2003A, ULN2004A, ULQ2004A**

SLRS0270 – DECEMBER 1976 – REVISED JANUARY 2016

www.ti.com

9.2.3 Application Curves

The characterization data shown in [Figure 23](#) and [Figure 24](#) were generated using the ULN2003A device driving an OMRON G5NB relay and under the following conditions: $V_{IN} = 5$ V, $V_{SUP} = 12$ V, and $R_{COIL} = 2.8$ k Ω .

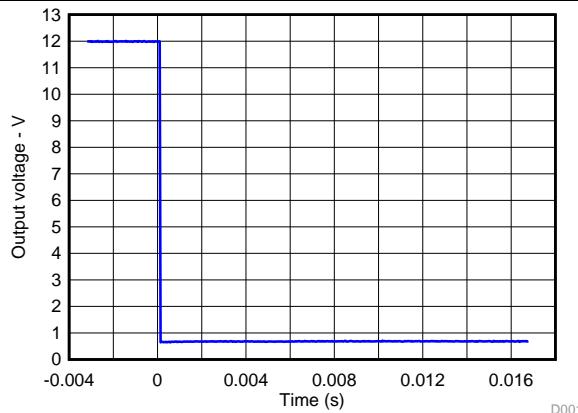


Figure 23. Output Response With Activation of Coil (Turnon)

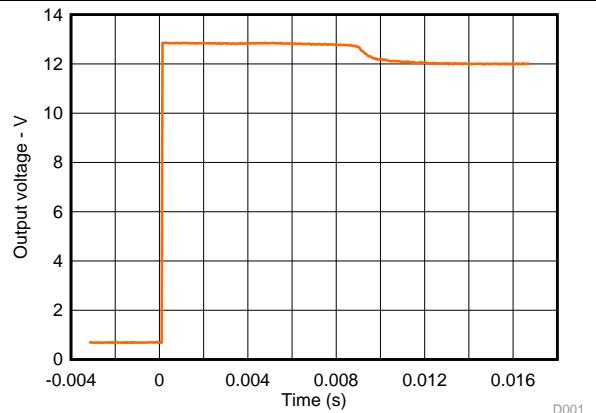


Figure 24. Output Response With De-activation of Coil (Turnoff)

9.3 System Examples

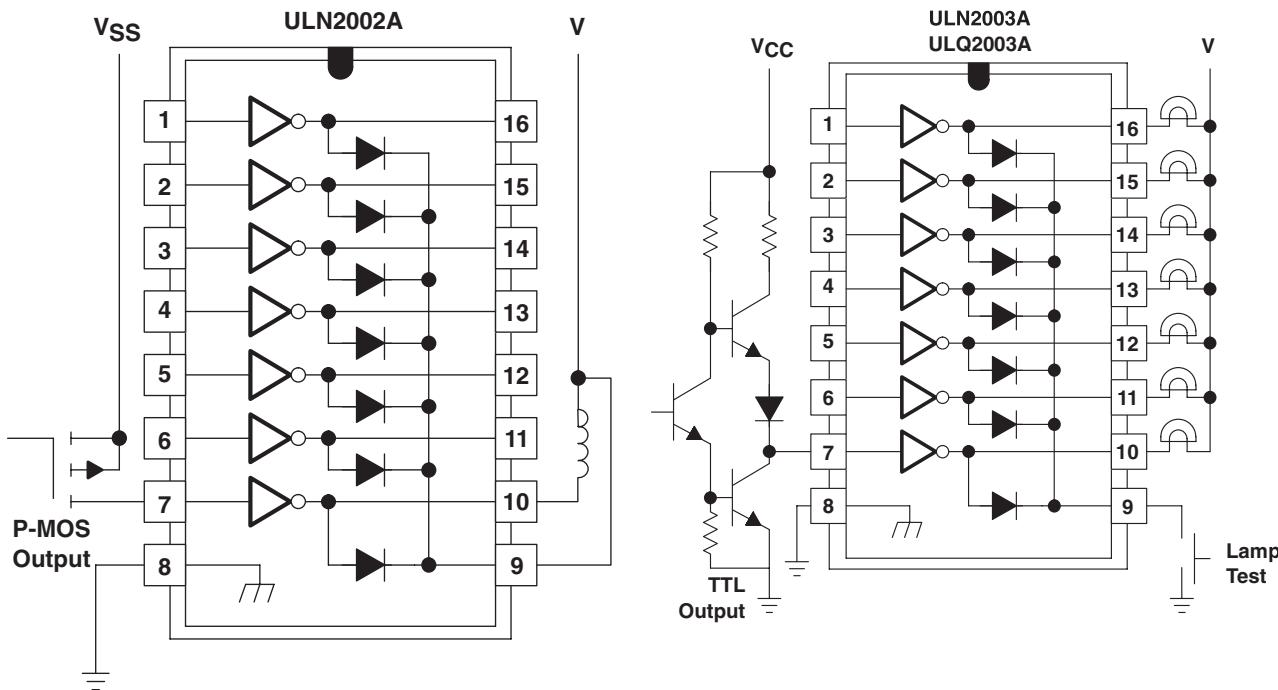


Figure 25. P-MOS to Load

Figure 26. TTL to Load

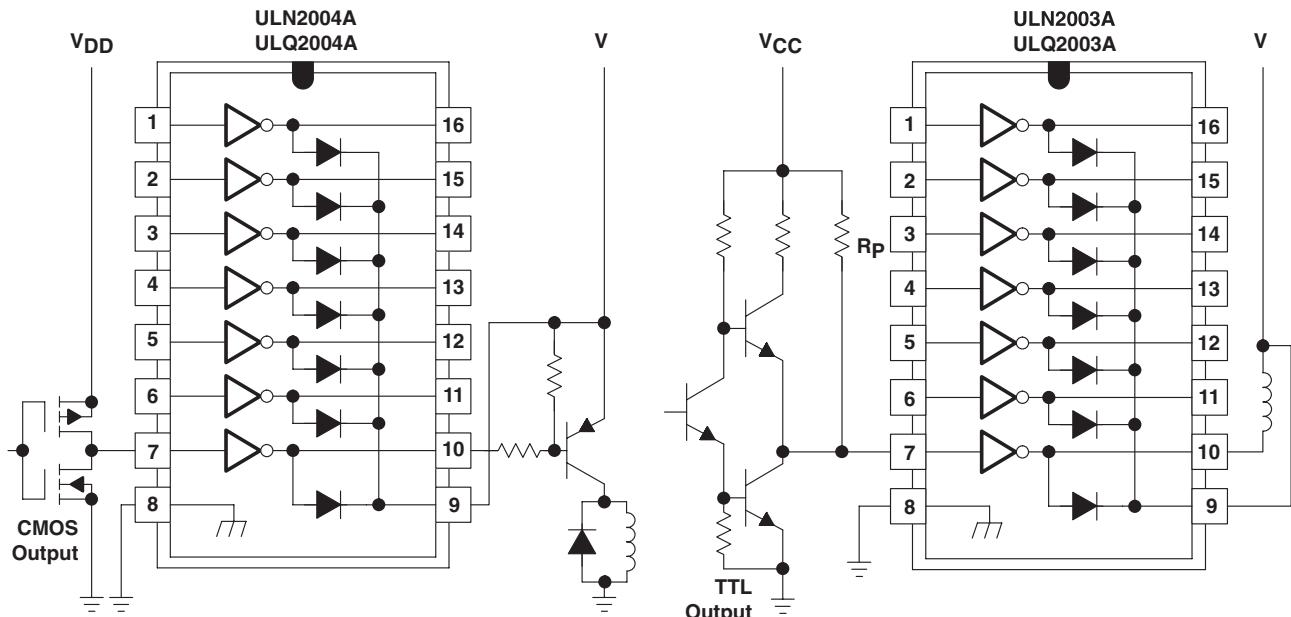


Figure 27. Buffer for Higher Current Loads

Figure 28. Use of Pullup Resistors to Increase Drive Current

ULN2002A, ULN2003A, ULN2003AI
ULQ2003A, ULN2004A, ULQ2004A

SLRS0270 – DECEMBER 1976 – REVISED JANUARY 2016

www.ti.com

10 Power Supply Recommendations

This device does not need a power supply. However, the COM pin is typically tied to the system power supply. When this is the case, it is very important to ensure that the output voltage does not heavily exceed the COM pin voltage. This discrepancy heavily forward biases the fly-back diodes and causes a large current to flow into COM, potentially damaging the on-chip metal or over-heating the device.

11 Layout

11.1 Layout Guidelines

Thin traces can be used on the input due to the low-current logic that is typically used to drive ULN2003A device. Take care to separate the input channels as much as possible, as to eliminate crosstalk. TI recommends thick traces for the output to drive whatever high currents that may be needed. Wire thickness can be determined by the current density of the trace material and desired drive current.

Because all of the channels currents return to a common emitter, it is best to size that trace width to be very wide. Some applications require up to 2.5 A.

11.2 Layout Example

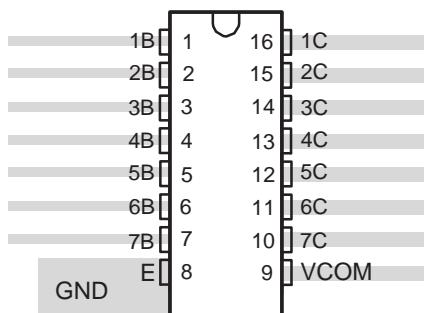


Figure 29. Package Layout

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation, see the following:

SN7546x Darlington Transistor Arrays, SLRS023

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
ULN2002A	Click here				
ULN2003A	Click here				
ULN2003AI	Click here				
ULN2004A	Click here				
ULQ2003A	Click here				
ULQ2004A	Click here				

12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.6 Glossary

[SLYZ022 — TI Glossary.](#)

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ULN2001AD	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI			
ULN2001ADR	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI			
ULN2001AN	OBSOLETE	PDIP	N	16		TBD	Call TI	Call TI			
ULN2002AD	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI			
ULN2002AN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-20 to 70	ULN2002AN	Samples
ULN2002ANE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-20 to 70	ULN2002AN	Samples
ULN2003AD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2003A	Samples
ULN2003ADE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2003A	Samples
ULN2003ADG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2003A	Samples
ULN2003ADR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-20 to 70	ULN2003A	Samples
ULN2003ADRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2003A	Samples
ULN2003ADRG3	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-20 to 70	ULN2003A	Samples
ULN2003ADRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2003A	Samples
ULN2003AID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2003AI	Samples
ULN2003AIDE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2003AI	Samples
ULN2003AIDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2003AI	Samples
ULN2003AIDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 105	ULN2003AI	Samples
ULN2003AIDRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2003AI	Samples
ULN2003AIDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2003AI	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ULN2003AIN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU CU SN	N / A for Pkg Type	-40 to 105	ULN2003AIN	Samples
ULN2003AINE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 105	ULN2003AIN	Samples
ULN2003AINS	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2003AI	Samples
ULN2003AIPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	UN2003AI	Samples
ULN2003AIPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	UN2003AI	Samples
ULN2003AIPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	UN2003AI	Samples
ULN2003AIPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 105	UN2003AI	Samples
ULN2003AIPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	UN2003AI	Samples
ULN2003AJ	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI	-55 to 125		
ULN2003AN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU CU SN	N / A for Pkg Type	-20 to 70	ULN2003AN	Samples
ULN2003ANE3	PREVIEW	PDIP	N	16		TBD	Call TI	Call TI	-20 to 70	ULN2003AN	
ULN2003ANE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-20 to 70	ULN2003AN	Samples
ULN2003ANSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2003A	Samples
ULN2003ANSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2003A	Samples
ULN2003ANSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2003A	Samples
ULN2003APW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	UN2003A	Samples
ULN2003APWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	UN2003A	Samples
ULN2003APWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-20 to 70	UN2003A	Samples
ULN2003APWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	UN2003A	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ULN2004AD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2004A	Samples
ULN2004ADE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2004A	Samples
ULN2004ADG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2004A	Samples
ULN2004ADR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-20 to 70	ULN2004A	Samples
ULN2004ADRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2004A	Samples
ULN2004ADRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2004A	Samples
ULN2004AN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-20 to 70	ULN2004AN	Samples
ULN2004ANE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-20 to 70	ULN2004AN	Samples
ULN2004ANSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2004A	Samples
ULQ2003AD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ULQ2003A	Samples
ULQ2003ADG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		ULQ2003A	Samples
ULQ2003ADR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ULQ2003A	Samples
ULQ2003ADRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		ULQ2003A	Samples
ULQ2003AN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	ULQ2003A	Samples
ULQ2004AD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ULQ2004A	Samples
ULQ2004ADG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		ULQ2004A	Samples
ULQ2004ADR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ULQ2004A	Samples
ULQ2004ADRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		ULQ2004A	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ULQ2004AN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	ULQ2004AN	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF ULQ2003A, ULQ2004A :



Distributor of Texas Instruments: Excellent Integrated System Limited

Datasheet of ULN2003AIDR - TRANS 7NPN DARL 50V 0.5A 16SO

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

PACKAGE OPTION ADDENDUM

www.ti.com

22-Jan-2016

- Automotive: [ULQ2003A-Q1](#), [ULQ2004A-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

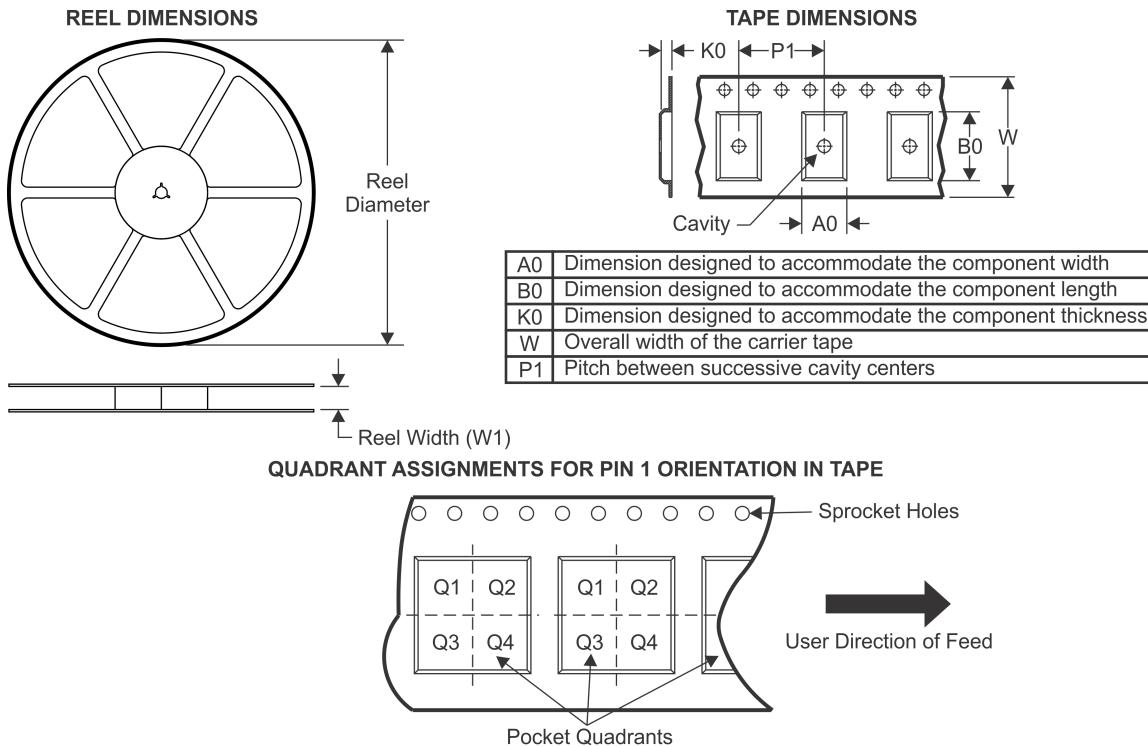


PACKAGE MATERIALS INFORMATION

www.ti.com

9-Aug-2016

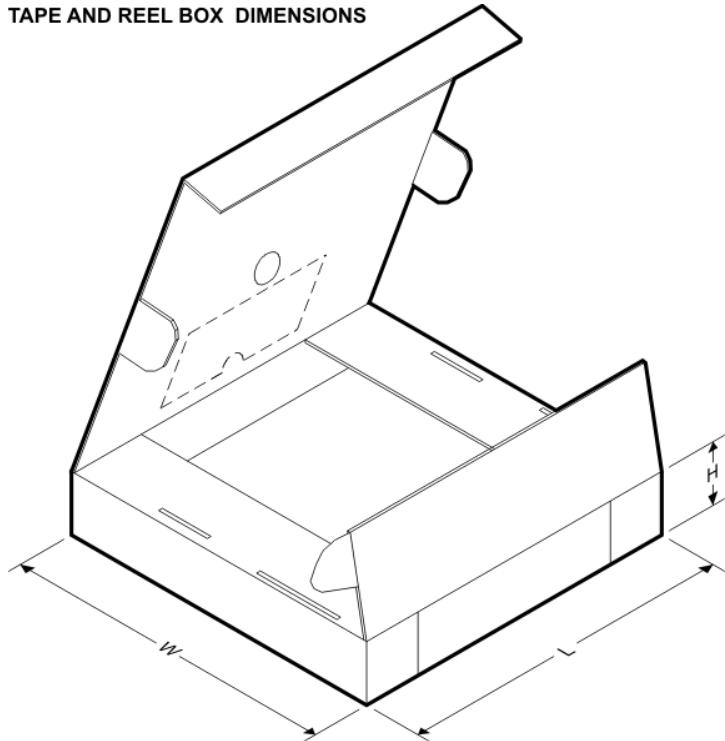
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ULN2003ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2003ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2003ADRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2003AIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2003AIDRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2003AIPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
ULN2003AIPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
ULN2003AIPWRG4	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
ULN2003APWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
ULN2003APWRG4	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
ULN2004ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2004ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2004ADR	SOIC	D	16	2500	330.0	16.8	6.5	10.3	2.1	8.0	16.0	Q1
ULN2004ADRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2004ADRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULQ2003ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULQ2003ADRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



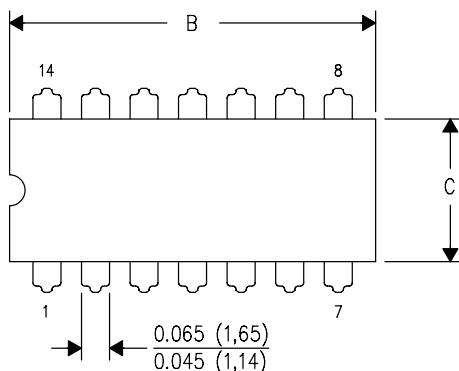
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ULN2003ADR	SOIC	D	16	2500	333.2	345.9	28.6
ULN2003ADR	SOIC	D	16	2500	367.0	367.0	38.0
ULN2003ADRG4	SOIC	D	16	2500	333.2	345.9	28.6
ULN2003AIDR	SOIC	D	16	2500	333.2	345.9	28.6
ULN2003AIDRG4	SOIC	D	16	2500	333.2	345.9	28.6
ULN2003AIPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
ULN2003AIPWR	TSSOP	PW	16	2000	364.0	364.0	27.0
ULN2003AIPWRG4	TSSOP	PW	16	2000	367.0	367.0	35.0
ULN2003APWR	TSSOP	PW	16	2000	367.0	367.0	35.0
ULN2003APWRG4	TSSOP	PW	16	2000	367.0	367.0	35.0
ULN2004ADR	SOIC	D	16	2500	367.0	367.0	38.0
ULN2004ADR	SOIC	D	16	2500	333.2	345.9	28.6
ULN2004ADR	SOIC	D	16	2500	364.0	364.0	27.0
ULN2004ADRG4	SOIC	D	16	2500	367.0	367.0	38.0
ULN2004ADRG4	SOIC	D	16	2500	333.2	345.9	28.6
ULQ2003ADR	SOIC	D	16	2500	333.2	345.9	28.6
ULQ2003ADRG4	SOIC	D	16	2500	367.0	367.0	38.0

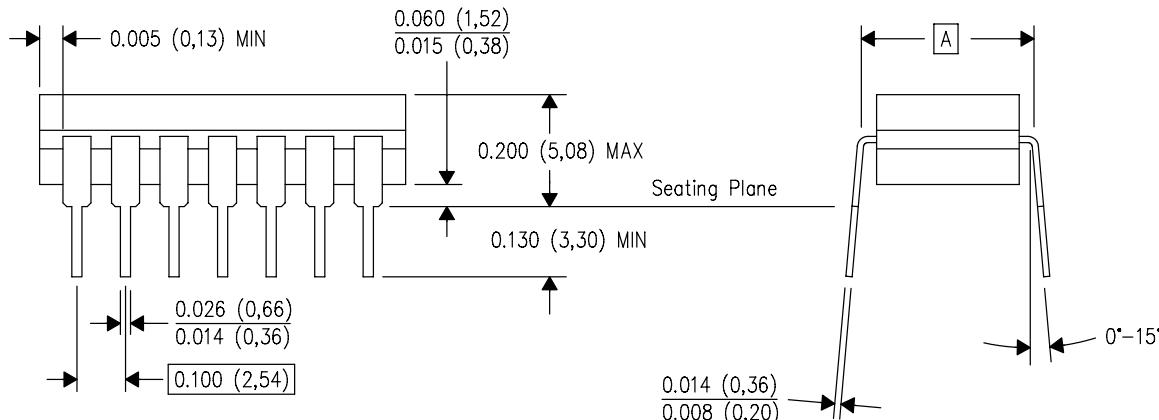
J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



DIM	PINS **	14	16	18	20
	A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX		0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN		—	—	—	—
C MAX		0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN		0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



4040083/F 03/03

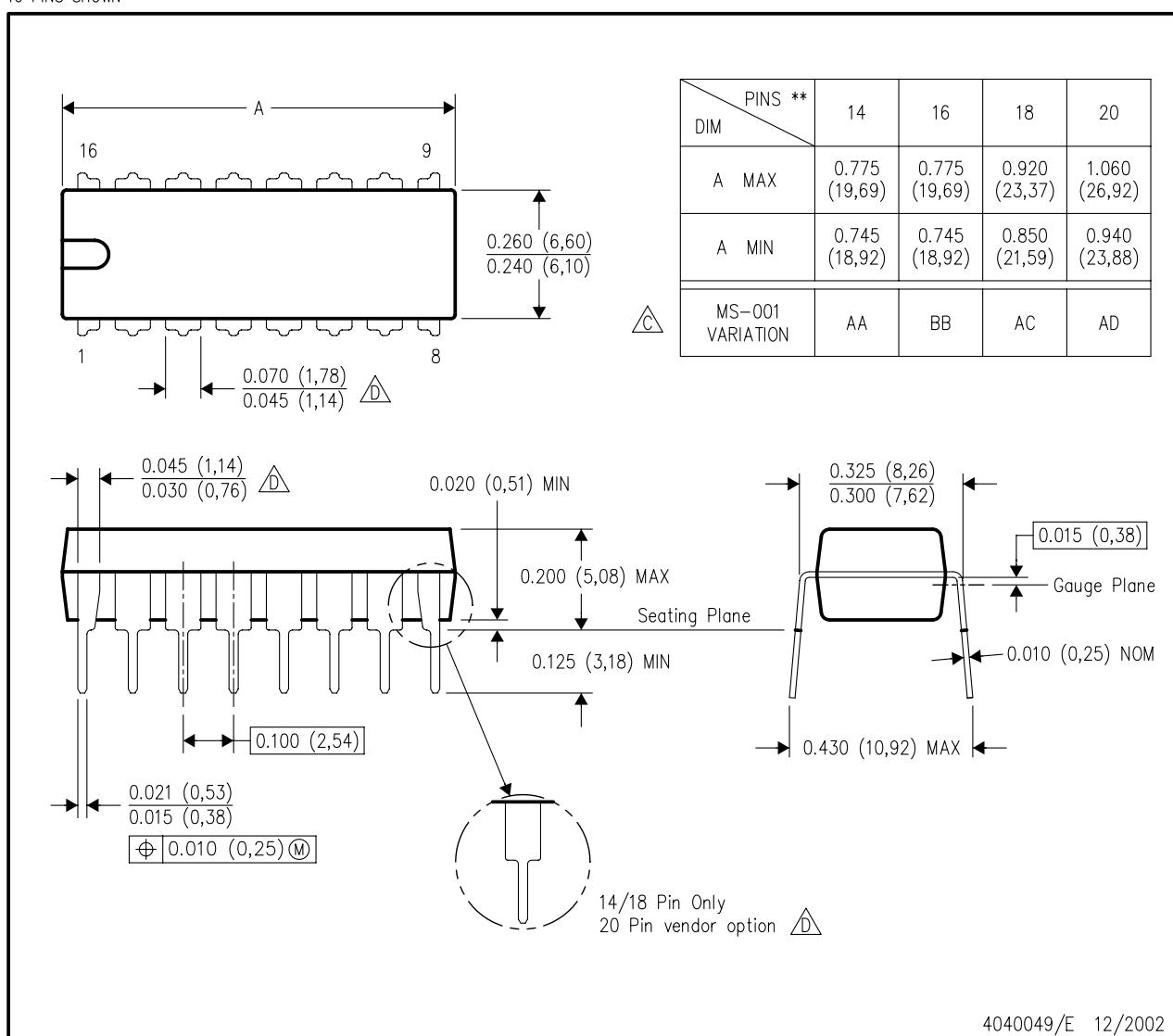
- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

MECHANICAL DATA

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.

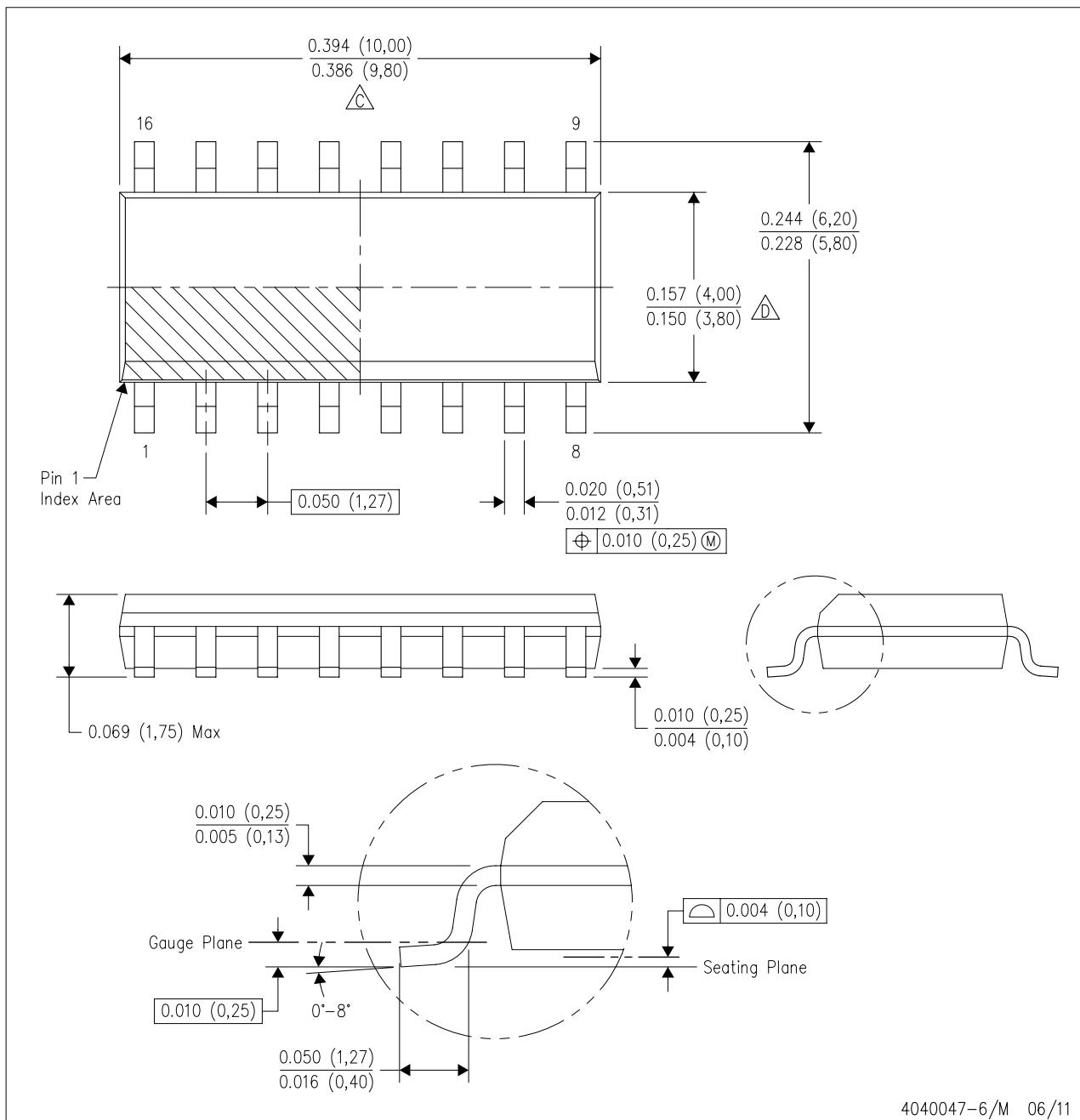
Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).

The 20 pin end lead shoulder width is a vendor option, either half or full width.

MECHANICAL DATA

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



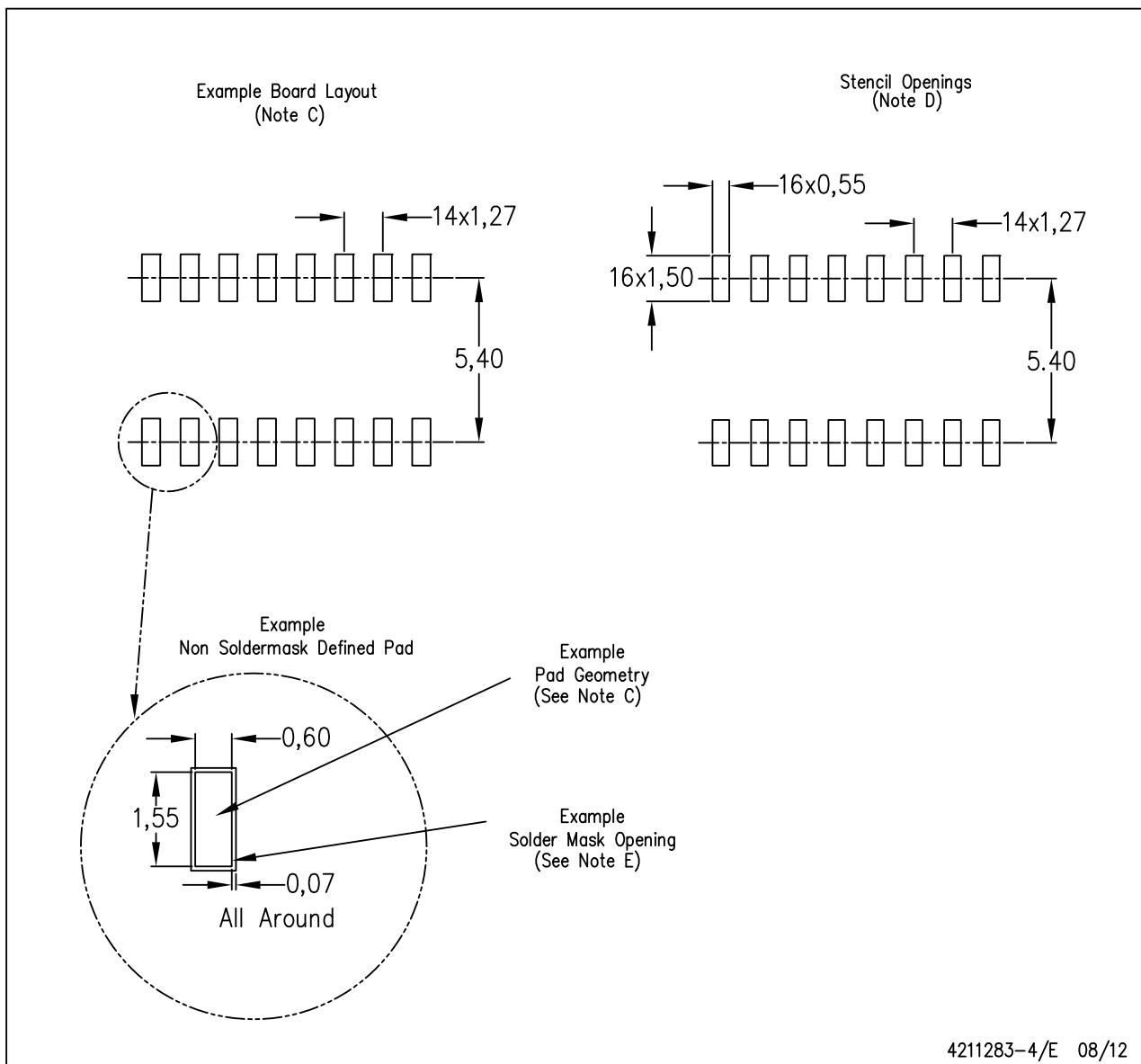
- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.

- C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- D Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.

LAND PATTERN DATA

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4211283-4/E 08/12

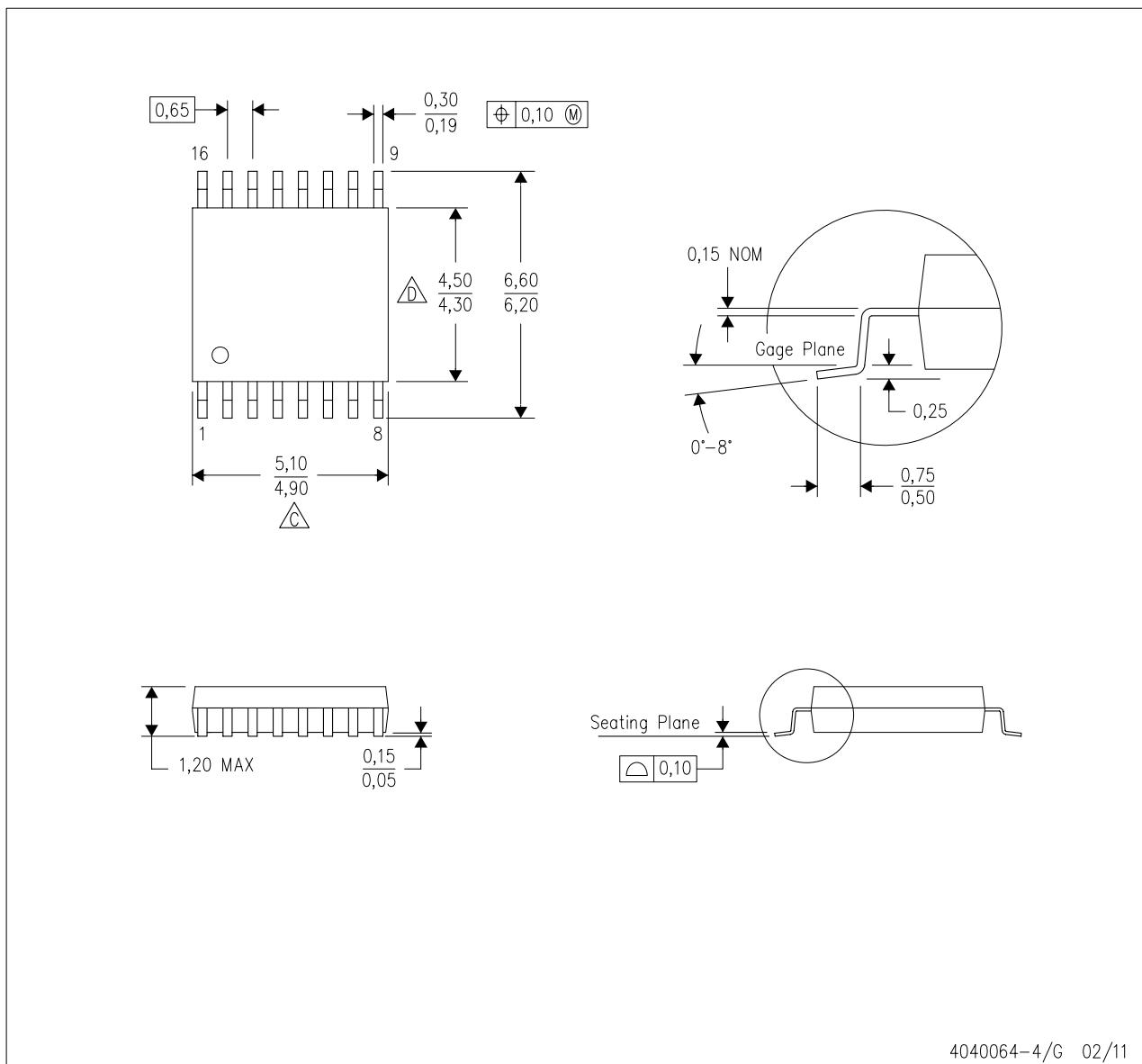
NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Publication IPC-7351 is recommended for alternate designs.
- Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

MECHANICAL DATA

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



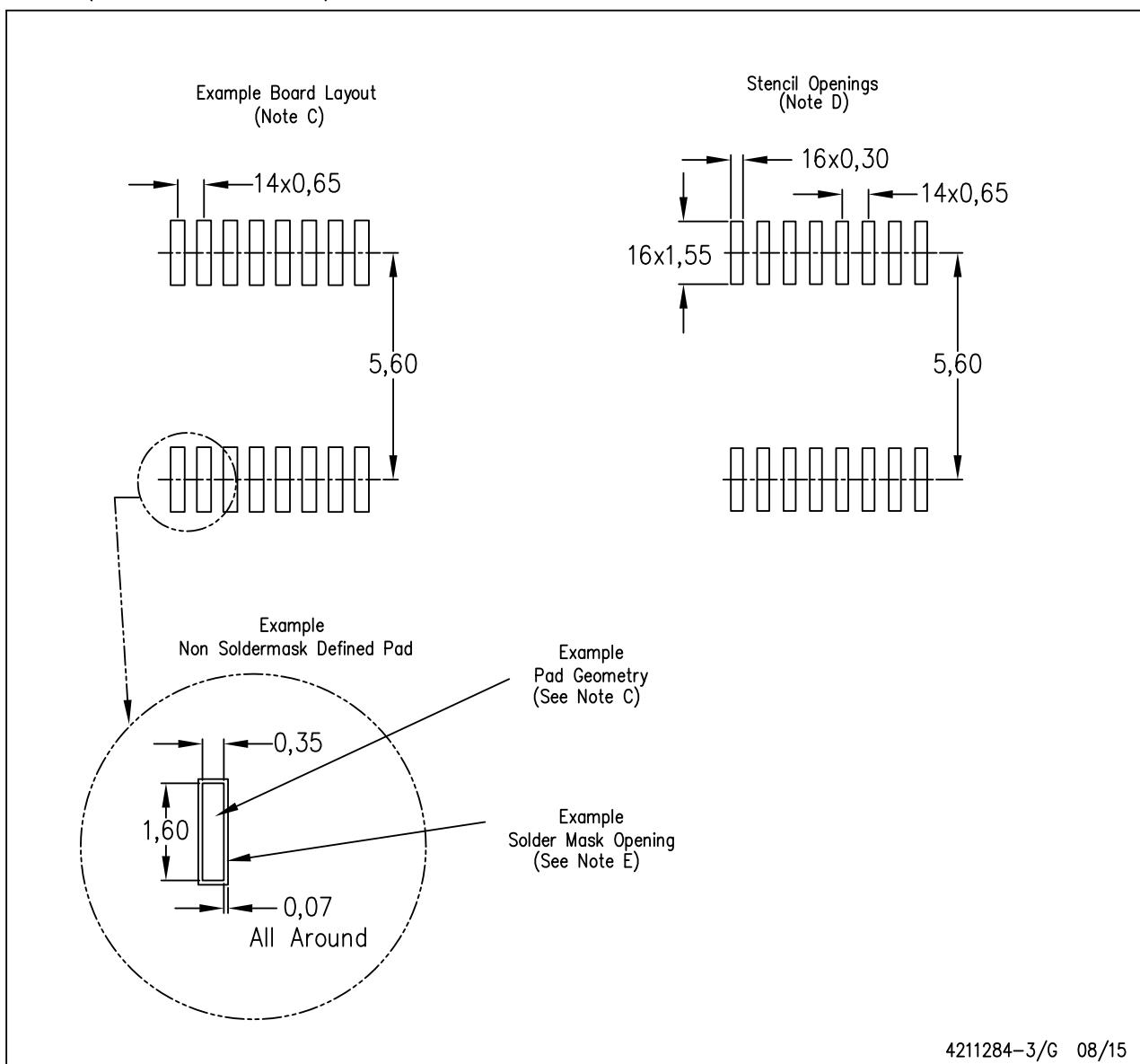
4040064-4/G 02/11

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 each side.
 - Body width does not include interlead flash. Interlead flash shall not exceed 0.25 each side.
 - Falls within JEDEC MO-153

LAND PATTERN DATA

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4211284-3/G 08/15

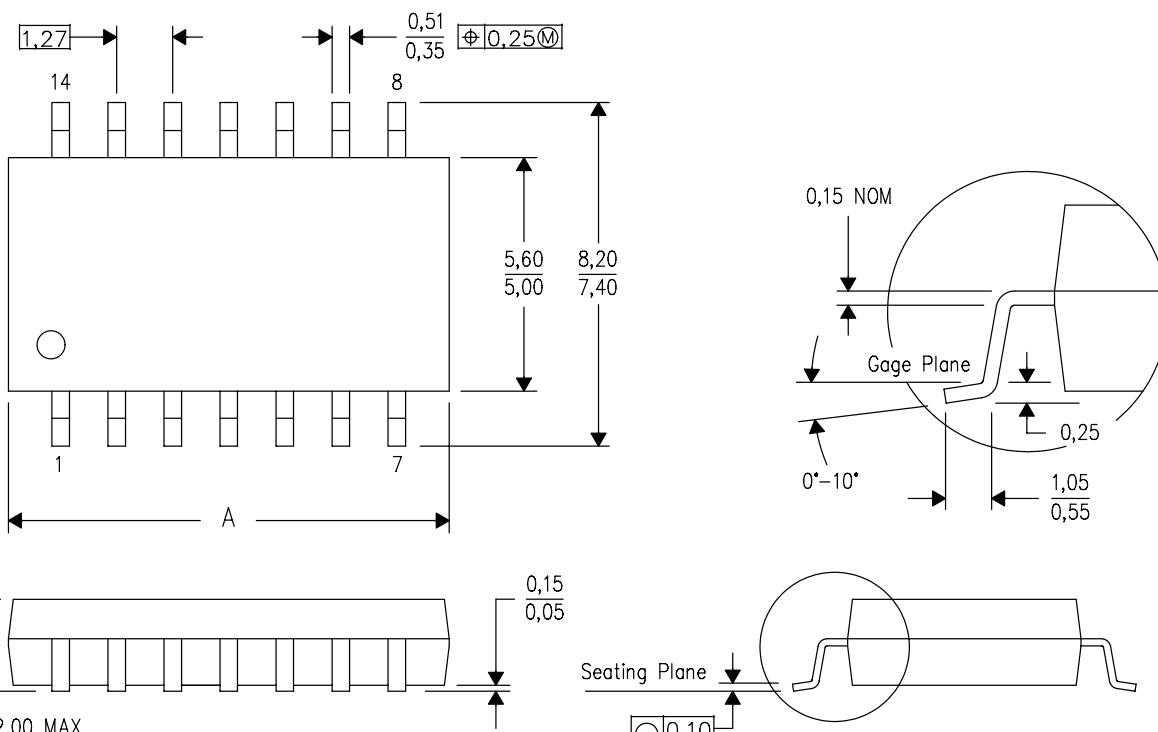
- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



PINS ** DIM	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com